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Reference Diode

General Description

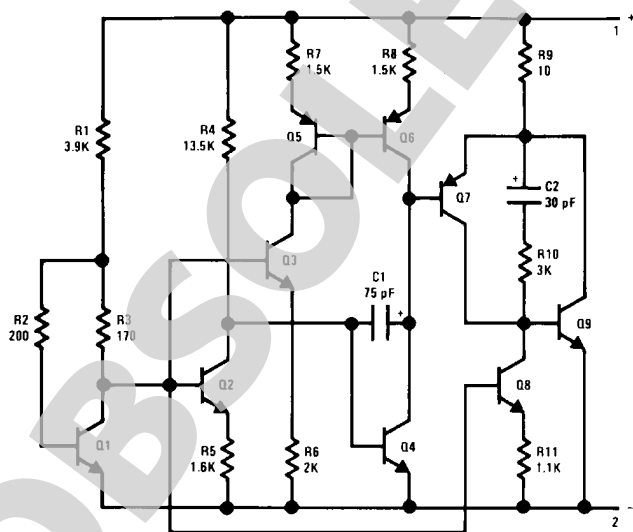
The LM113/LM313 are temperature compensated, low voltage reference diodes. They feature extremely-tight regulation over a wide range of operating currents in addition to an unusually-low breakdown voltage and good temperature stability.

The diodes are synthesized using transistors and resistors in a monolithic integrated circuit. As such, they have the same low noise and long term stability as modern IC op amps. Further, output voltage of the reference depends only on highly-predictable properties of components in the IC; so they can be manufactured and supplied to tight tolerances.

Features

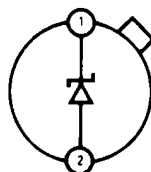
- Low breakdown voltage: 1.220V
 - Dynamic impedance of 0.3Ω from $500\ \mu\text{A}$ to $20\ \text{mA}$
 - Temperature stability typically 1% over -55°C to 125°C range (LM113), 0°C to 70°C (LM313)
 - Tight tolerance: $\pm 5\%$, $\pm 2\%$ or $\pm 1\%$
- The characteristics of this reference recommend it for use in bias-regulation circuitry, in low-voltage power supplies or in battery powered equipment. The fact that the breakdown voltage is equal to a physical property of silicon—the energy-band gap voltage—makes it useful for many temperature-compensation and temperature-measurement functions.

Schematic and Connection Diagrams



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Metal Can Package

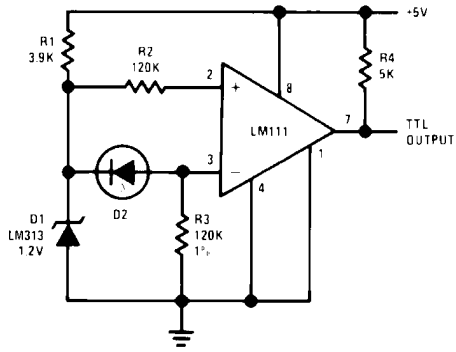


Note: Pin 2 connected to case.
TOP VIEW

Order Number LM113H, LM113H/883, LM113-1H, LM113-1H/883, LM113-2H, LM113-2H/883 or LM313H
See NS Package Number H02A

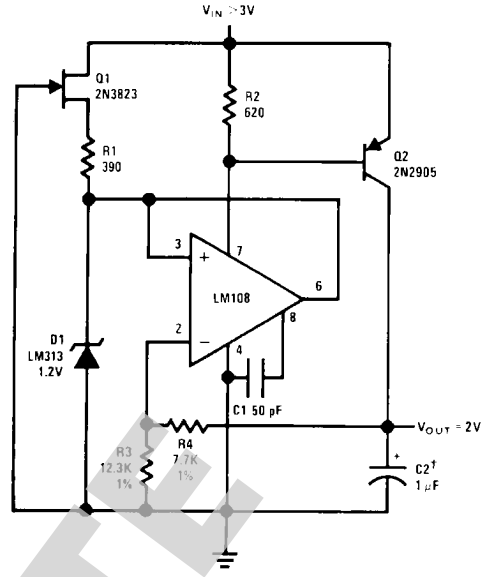
Typical Applications

Level Detector for Photodiode



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Low Voltage Regulator



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†Solid tantalum.

OBSOLETE

Absolute Maximum Ratings (Note 3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Power Dissipation (Note 1)	100 mW
Reverse Current	50 mA
Forward Current	50 mA

Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10 seconds)	300°C
Operating Temperature Range	
LM113	-55°C to +125°C
LM313	0°C to +70°C

Electrical Characteristics (Note 2)

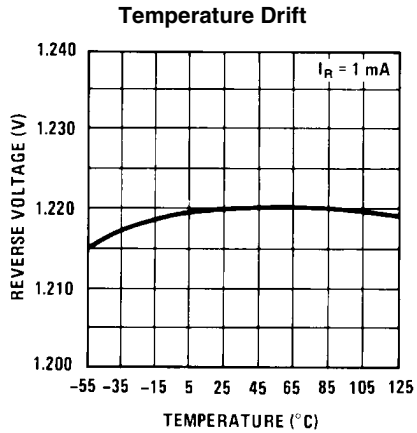
Parameter	Conditions	Min	Typ	Max	Units
Reverse Breakdown Voltage					
LM113/LM313	$I_R = 1 \text{ mA}$	1.160	1.220	1.280	V
LM113-1		1.210	1.22	1.232	V
LM113-2		1.195	1.22	1.245	V
Reverse Breakdown Voltage Change	$0.5 \text{ mA} \leq I_R \leq 20 \text{ mA}$		6.0	15	mV
Reverse Dynamic Impedance	$I_R = 1 \text{ mA}$ $I_R = 10 \text{ mA}$		0.2 0.25	1.0 0.8	Ω
Forward Voltage Drop	$I_F = 1.0 \text{ mA}$		0.67	1.0	V
RMS Noise Voltage	$10 \text{ Hz} \leq f \leq 10 \text{ kHz}$ $I_R = 1 \text{ mA}$		5		μV
Reverse Breakdown Voltage Change with Current	$0.5 \text{ mA} \leq I_R \leq 10 \text{ mA}$ $T_{\text{MIN}} \leq T_A \leq T_{\text{MAX}}$			15	mV
Breakdown Voltage Temperature Coefficient	$1.0 \text{ mA} \leq I_R \leq 10 \text{ mA}$ $T_{\text{MIN}} \leq T_A \leq T_{\text{MAX}}$		0.01		%/°C

Note 1: For operating at elevated temperatures, the device must be derated based on a 150°C maximum junction and a thermal resistance of 80°C/W junction to case or 440°C/W junction to ambient.

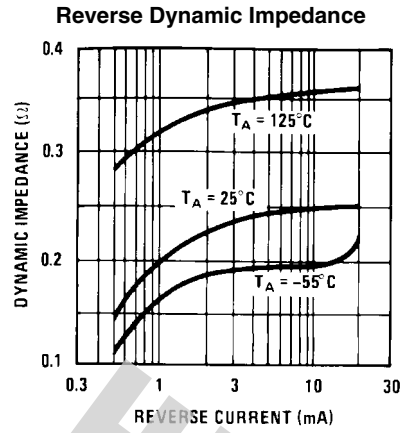
Note 2: These specifications apply for $T_A = 25^\circ\text{C}$, unless stated otherwise. At high currents, breakdown voltage should be measured with lead lengths less than ¼ inch. Kelvin contact sockets are also recommended. The diode should not be operated with shunt capacitances between 200 pF and 0.1 μF , unless isolated by at least a 100 Ω resistor, as it may oscillate at some currents.

Note 3: Refer to the following RETS drawings for military specifications: RETS113-1X for LM113-1, RETS113-2X for LM113-2 or RETS113X for LM113.

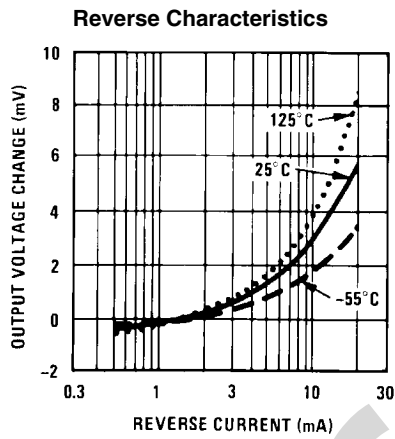
Typical Performance Characteristics



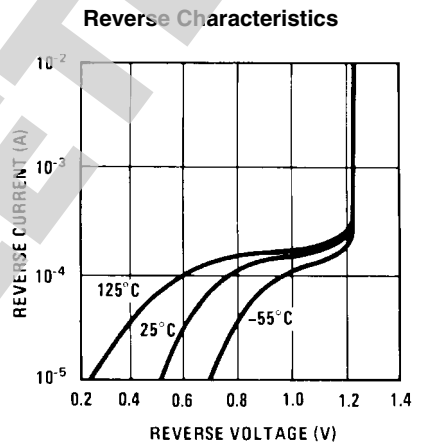
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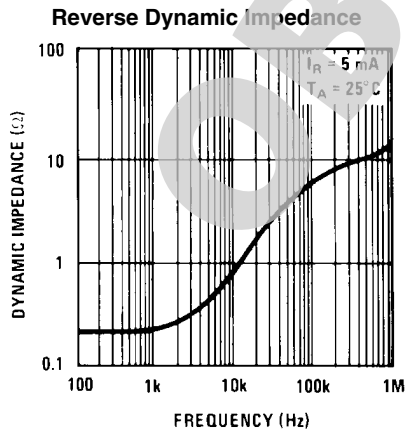
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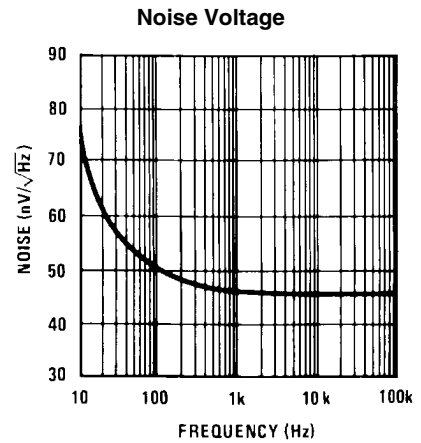
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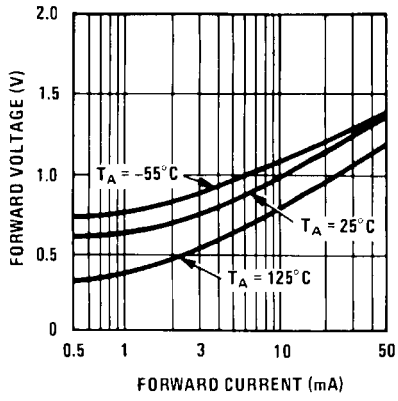


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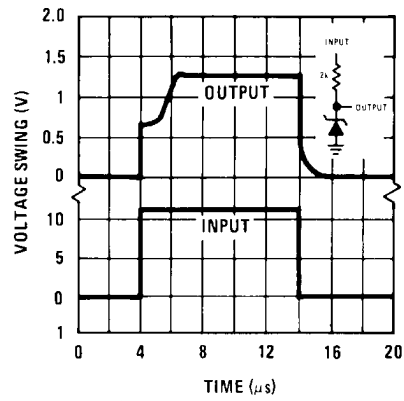
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Forward Characteristics



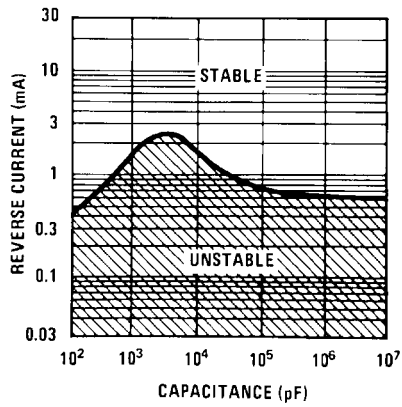
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Response Time



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Maximum Shunt Capacitance

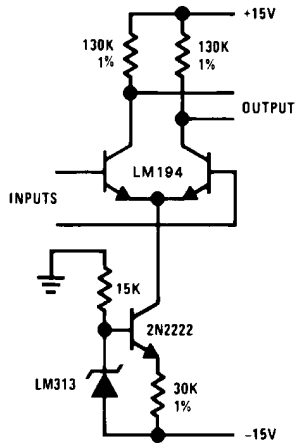


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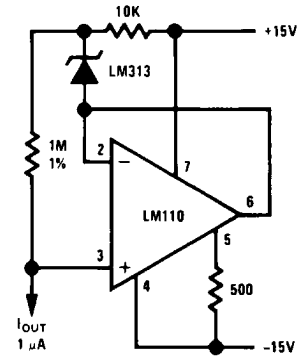
Typical Applications

Amplifier Biasing for Constant Gain with Temperature



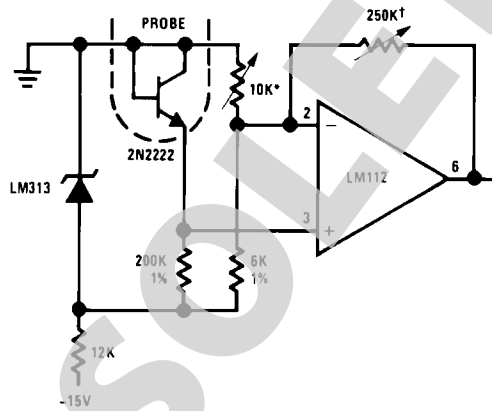
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Constant Current Source



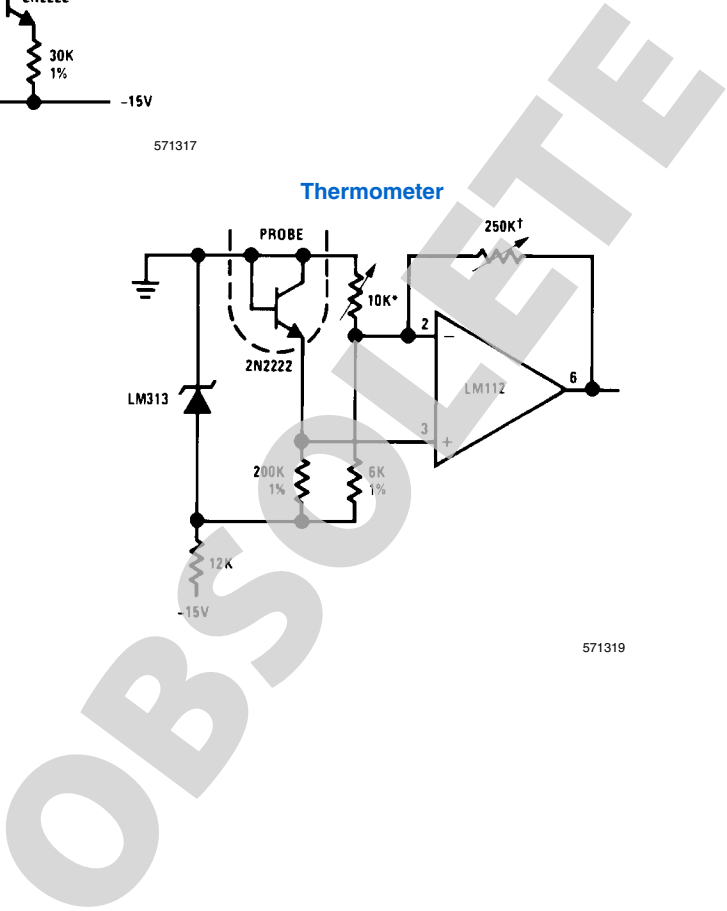
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Thermometer



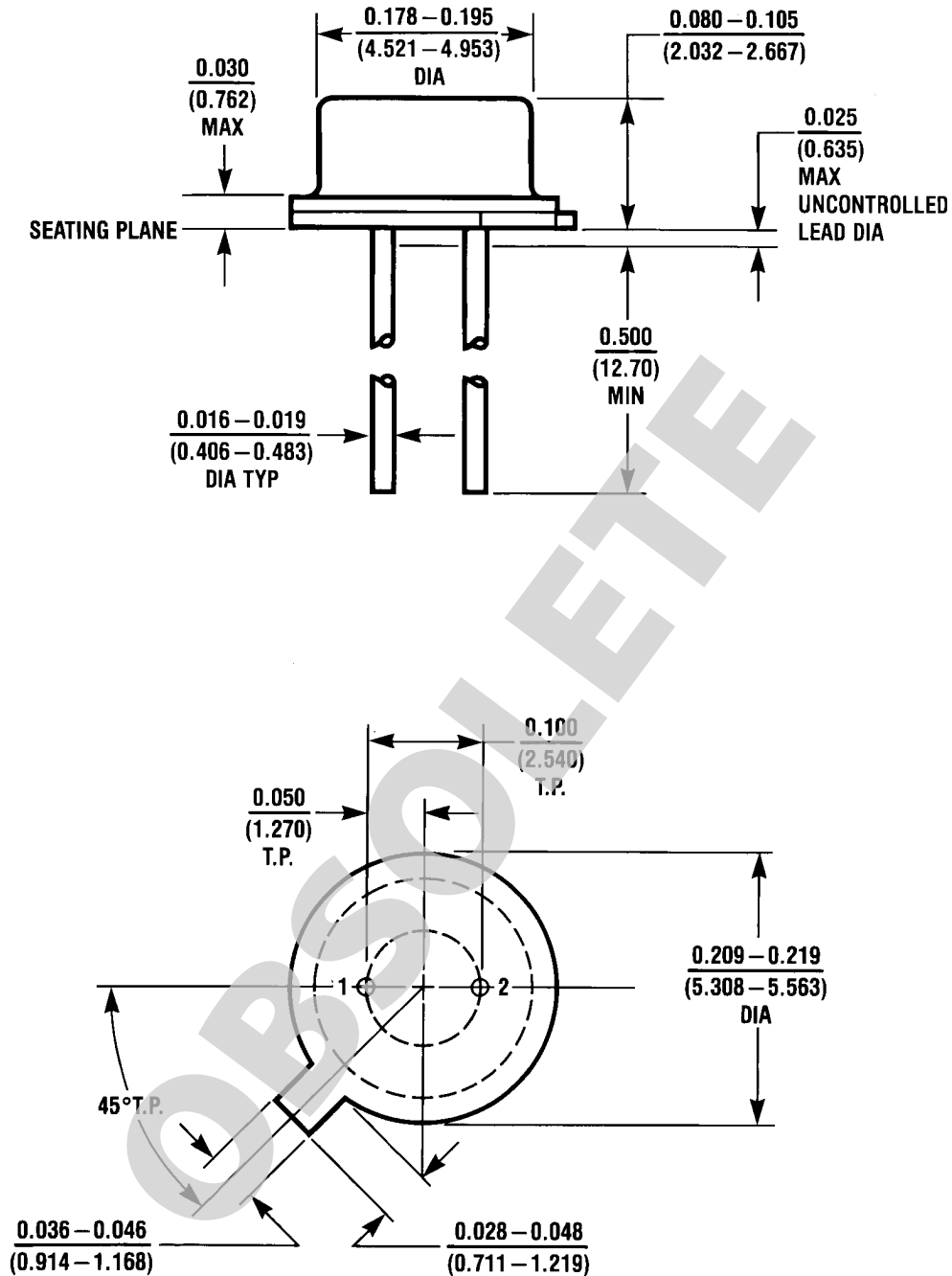
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Adjust for 0V at 0°C
Adjust for 100 mV/°C



Physical Dimensions

inches (millimeters) unless otherwise noted



H02A (REV C)

Order Number LM113H, LM113H/883, LM113-1H, LM113-1H/883,
LM113-2H, LM113-2H/883 or LM313H
NS Package Number H02A

Notes

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